

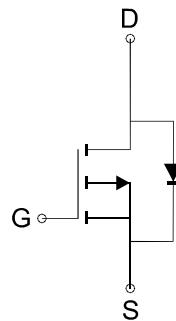
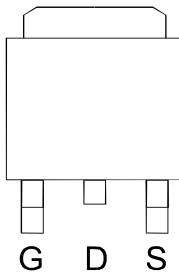
P- Channel 40-V (D-S) MOSFET
GENERAL DESCRIPTION

The ME12P04 is the P-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance. These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits where high-side switching, and low in-line power loss are needed in a very small outline surface mount package.

PIN CONFIGURATION

(TO-252-3L)

Top View



P-Channel MOSFET

Ordering Information: ME12P04 (Pb-free)

ME12P04-G (Green product-Halogen free)

Absolute Maximum Ratings (T_c=25°C Unless Otherwise Noted)

Parameter	Symbol	Maximum Ratings	Unit
Drain-Source Voltage	V _{DS}	-40	V
Gate-Source Voltage	V _{GS}	± 25	V
Continuous Drain Current	I _D	-18.6	A
T _c =70°C		-15	
Pulsed Drain Current	I _{DM}	-75	A
Maximum Power Dissipation	P _D	25	W
T _c =70°C		16	
Operating Junction Temperature	T _J	-55 to 150	°C
Thermal Resistance-Junction to Case*	R _{θJC}	5	°C/W

 *The device mounted on 1in² FR4 board with 2 oz copper


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Electrical Characteristics (T_C =25°C Unless Otherwise Specified)

Symbol	Parameter	Limit	Min	Typ	Max	Unit
STATIC						
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =-250 μA	-40			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =-250 μA	-1	-1.9	-3	V
I _{GSS}	Gate Leakage Current	V _{DS} =0V, V _{GS} =±25V			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =-40V, V _{GS} =0V			-1	μA
R _{DS(ON)}	Drain-Source On-State Resistance ^a	V _{GS} =-10V, I _D = -12A		35	45	mΩ
		V _{GS} =-4.5V, I _D = -6A		57	80	
V _{SD}	Diode Forward Voltage	I _S =-1.7A, V _{GS} =0V		-0.78	-1.2	V
DYNAMIC						
Q _g	Total Gate Charge	V _{DS} =-20V, V _{GS} =-10V, I _D =-12A		20.3		nC
Q _g	Total Gate Charge			9.8		
Q _{gs}	Gate-Source Charge	V _{DS} =-20V, V _{GS} =-4.5V, I _D =-12A		5		
Q _{gd}	Gate-Drain Charge			4.3		
C _{iss}	Input capacitance	V _{DS} =-20V, V _{GS} =0V, F=1MHz		921		pF
C _{oss}	Output Capacitance			91		
C _{rss}	Reverse Transfer Capacitance			78		
t _{d(on)}	Turn-On Delay Time	V _{DS} =-15V, R _L =15Ω V _{GS} =-10V, R _G =6Ω I _D =-1A,		35.3		ns
t _r	Turn-On Rise Time			56		
t _{d(off)}	Turn-Off Delay Time			15.6		
t _f	Turn-Off Fall Time			8.2		

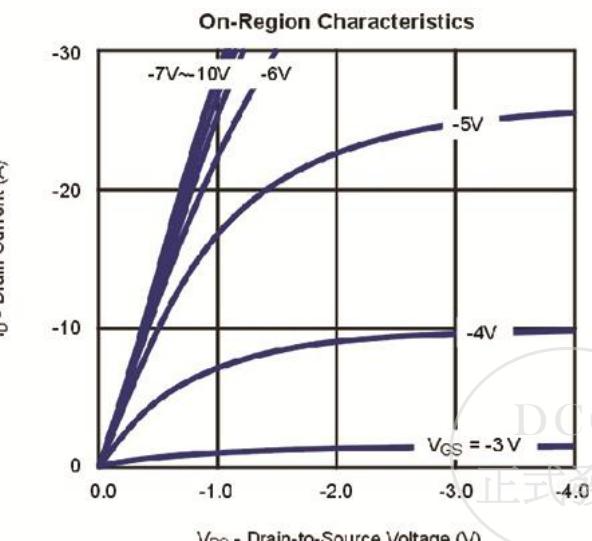
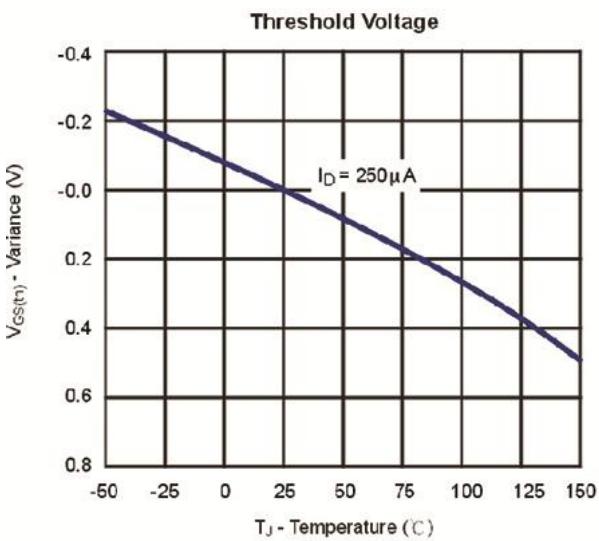
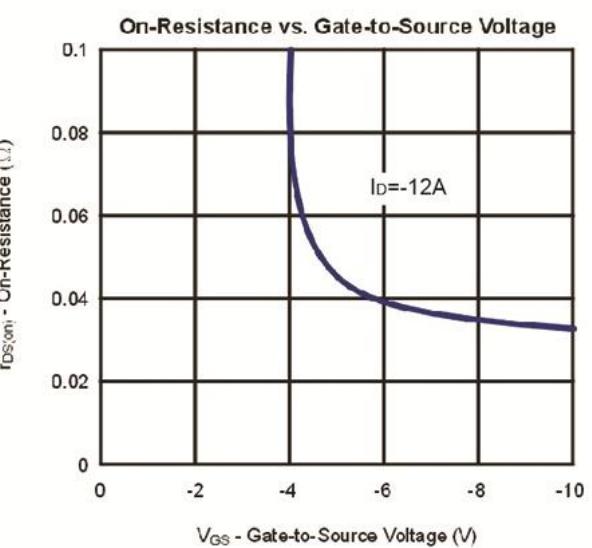
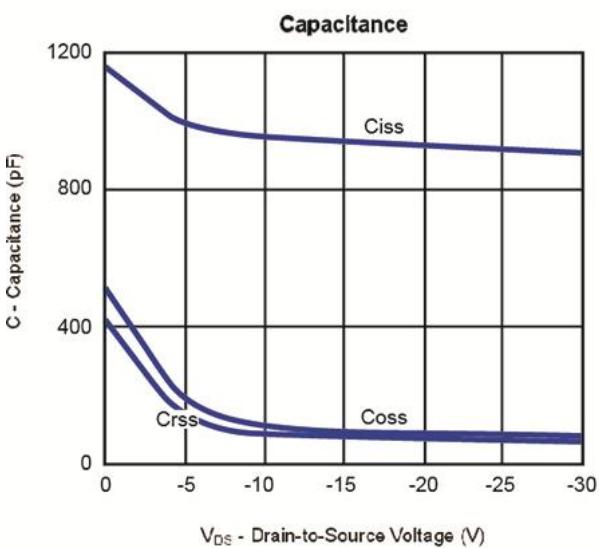
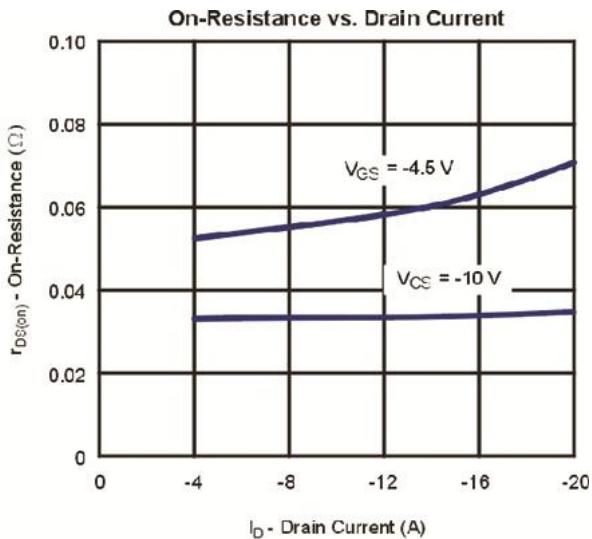
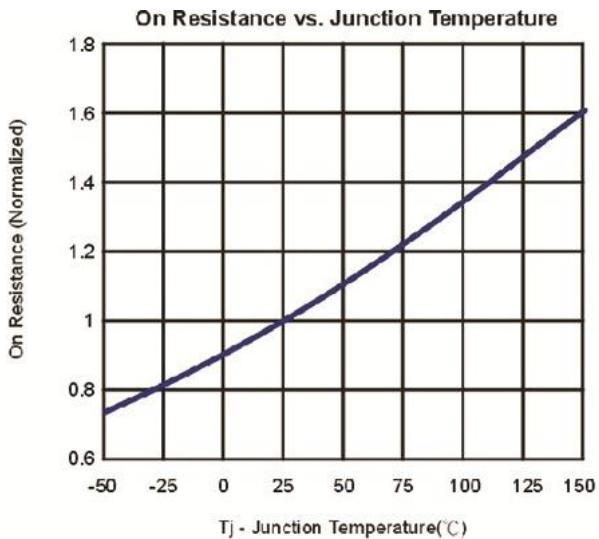
Notes:a. Pulse test; pulse width ≤ 300us, duty cycle≤ 2%

b. Matsuki Electric/ Force mos reserves the right to improve product design, functions and reliability without notice.



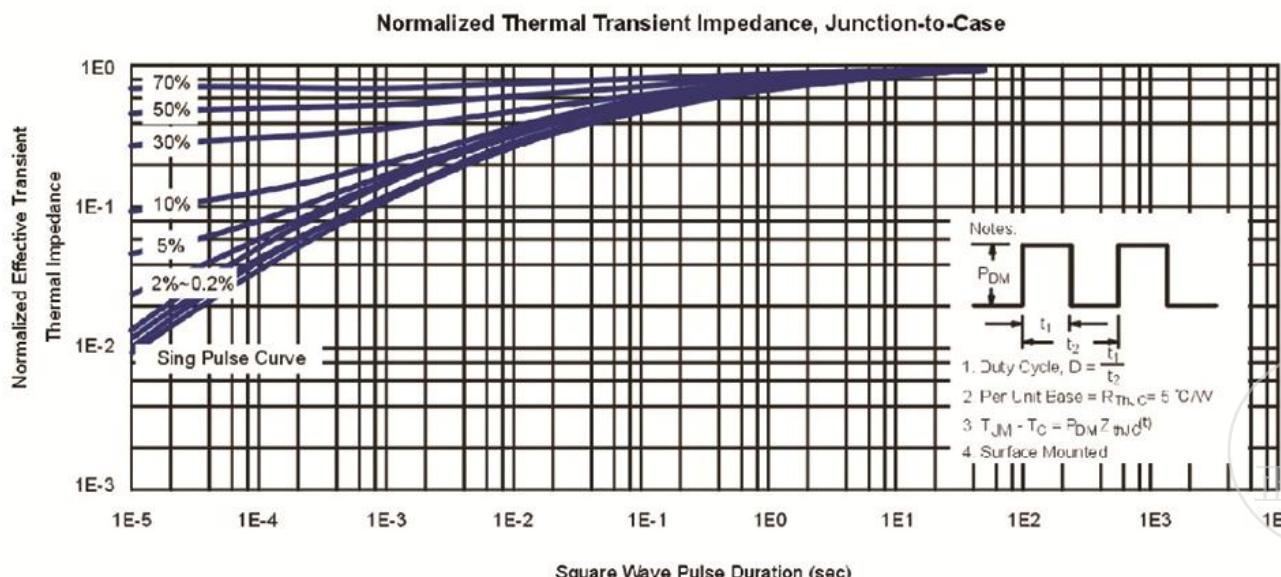
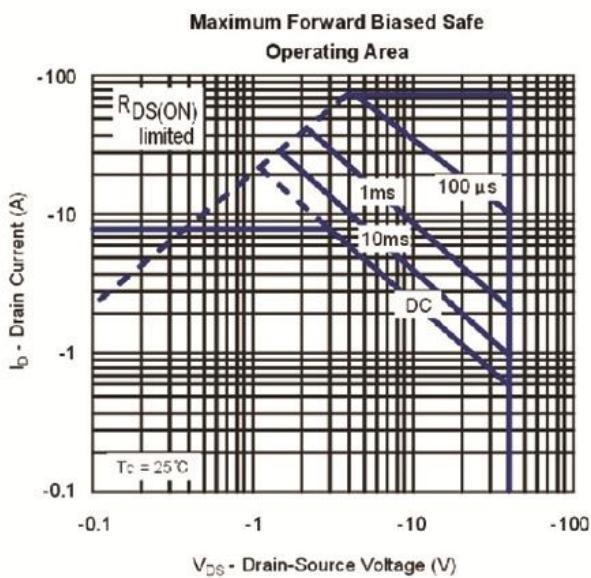
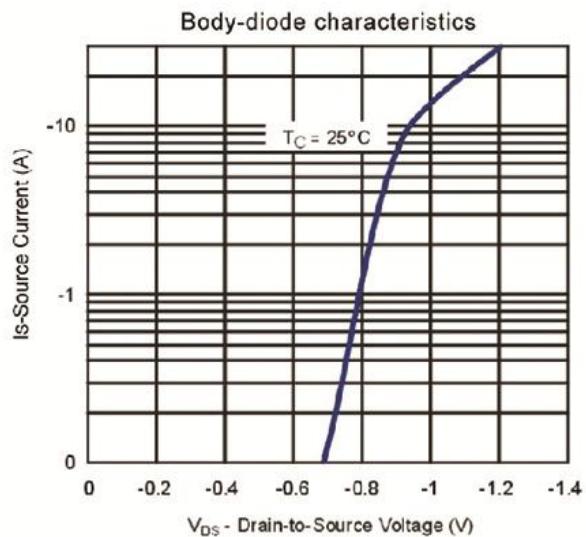
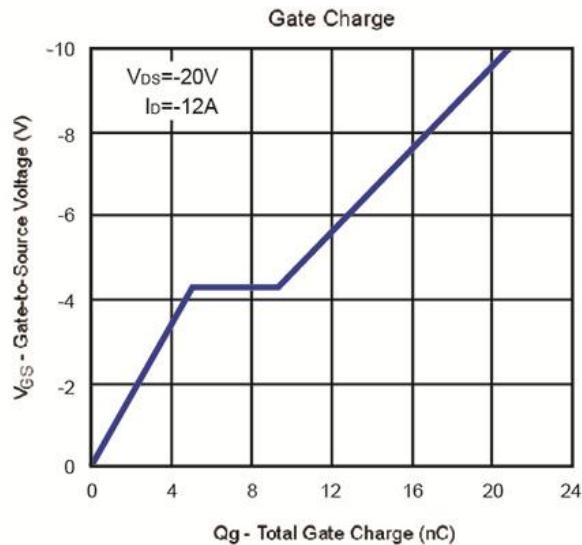
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Typical Characteristics (T_J = 25°C Noted)

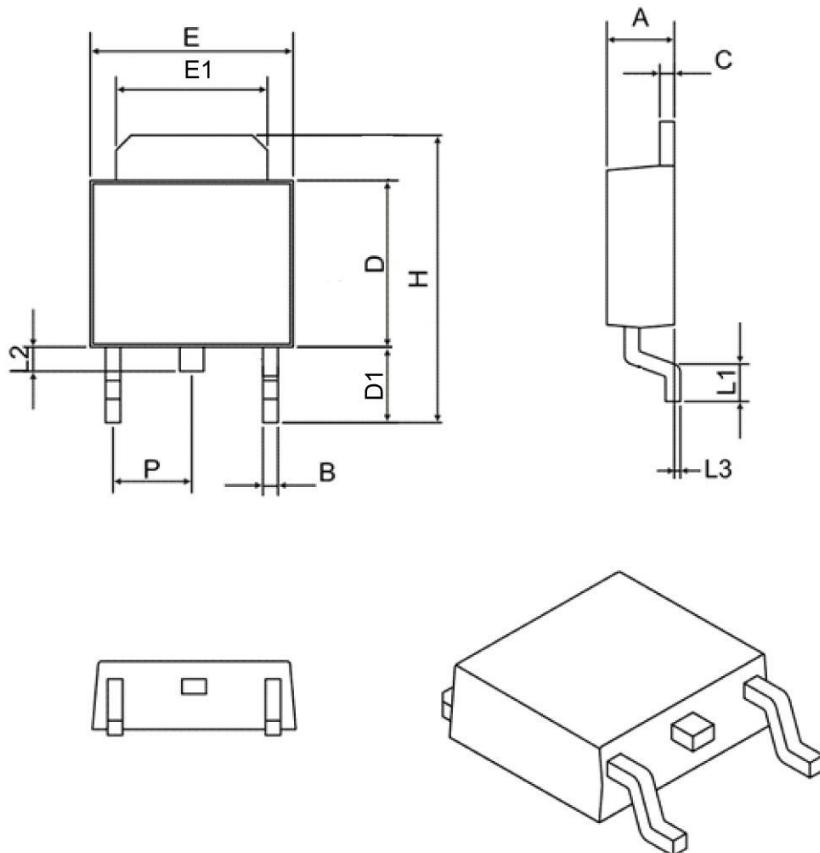


P- Channel 40-V (D-S) MOSFET

Typical Characteristics (T_J = 25°C Noted)



TO-252-3L Package Outline



SYMBOL	MIN	MAX
A	2.10	2.50
B	0.40	0.90
C	0.40	0.90
D	5.30	6.30
D1	2.20	2.90
E	6.30	6.75
E1	4.80	5.50
L1	0.90	1.80
L2	0.50	1.10
L3	0.00	0.20
H	8.90	10.40
P	2.30 BSC	



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